



Datasheet

HCA-S-200M-SI

200 MHz Photoreceiver with Si PIN Photodiode



The picture shows the HCA-S-200M-SI-FS with free space input. The photoreceiver will be delivered without post holder and post.

Features	<ul style="list-style-type: none"> • Si PIN Detector, 0.8 mm Active Diameter • Spectral Range 320 ... 1000 nm • Bandwidth DC ... 200 MHz • Amplifier Transimpedance (Gain) 2.0×10^4 V/A • Max. Conversion Gain 1.1×10^4 V/W @ 800 nm 																																	
Applications	<ul style="list-style-type: none"> • Spectroscopy • Fast Pulse and Transient Measurements • Optical Triggering • Optical Front-End for Oscilloscopes, A/D Converters and HF Lock-In Amplifiers 																																	
Specifications	<table border="0"> <tr> <td></td> <td><i>Test Conditions</i></td> <td><i>V_s = ± 15 V, T_a = 25°C</i></td> </tr> <tr> <td rowspan="2">Gain</td> <td>Transimpedance</td> <td>2.0×10^4 V/A (@ 50 Ω load)</td> </tr> <tr> <td>Max. Conversion Gain</td> <td>1.1×10^4 V/W (@ 800 nm)</td> </tr> <tr> <td rowspan="4">Frequency Response</td> <td>Lower Cut-Off Frequency</td> <td>DC</td> </tr> <tr> <td>Upper Cut-Off Frequency (- 3 dB)</td> <td>200 MHz (± 10 %)</td> </tr> <tr> <td>Rise/Fall Time (10% - 90%)</td> <td>1.8 ns</td> </tr> <tr> <td>Gain Flatness</td> <td>± 1 dB</td> </tr> <tr> <td rowspan="3">Detector</td> <td>Detector Material</td> <td>Si PIN photodiode</td> </tr> <tr> <td>Active Area</td> <td>Ø 0.8 mm</td> </tr> <tr> <td>Spectral Response</td> <td>320 ... 1000 nm</td> </tr> <tr> <td>Input</td> <td colspan="2">Input Offset Compensation Range: ± 100 nA adjustable by offset trim pot</td> </tr> <tr> <td></td> <td>Optical Saturation Power</td> <td>110 μW (for linear amplification, @ 800 nm)</td> </tr> <tr> <td></td> <td>Min. NEP</td> <td>9.4 pW/√Hz (@ 800 nm, 10 MHz)</td> </tr> </table>		<i>Test Conditions</i>	<i>V_s = ± 15 V, T_a = 25°C</i>	Gain	Transimpedance	2.0×10^4 V/A (@ 50 Ω load)	Max. Conversion Gain	1.1×10^4 V/W (@ 800 nm)	Frequency Response	Lower Cut-Off Frequency	DC	Upper Cut-Off Frequency (- 3 dB)	200 MHz (± 10 %)	Rise/Fall Time (10% - 90%)	1.8 ns	Gain Flatness	± 1 dB	Detector	Detector Material	Si PIN photodiode	Active Area	Ø 0.8 mm	Spectral Response	320 ... 1000 nm	Input	Input Offset Compensation Range: ± 100 nA adjustable by offset trim pot			Optical Saturation Power	110 μW (for linear amplification, @ 800 nm)		Min. NEP	9.4 pW/√Hz (@ 800 nm, 10 MHz)
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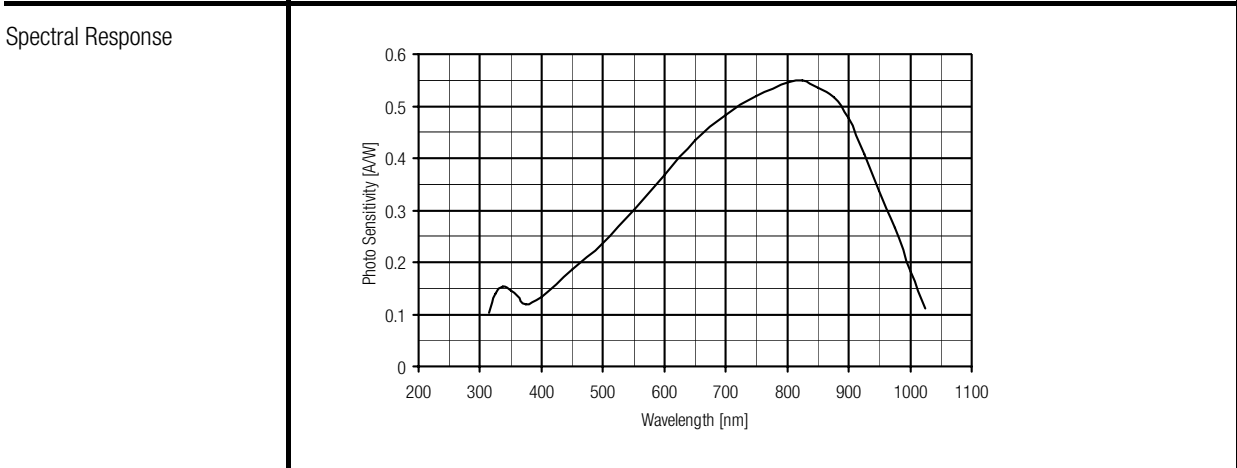
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HCA-S-200M-SI

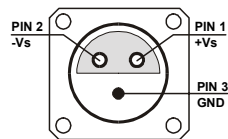
200 MHz Photoreceiver with Si PIN Photodiode

Specifications (continued)	
Output	Output Voltage Range $\pm 1.2\text{ V}$ (@ 50 Ω load) for linear operation and low harmonic distortion Max. Output Voltage Range $\pm 1.7\text{ V}$ (@ 50 Ω load) Output Impedance 50 Ω (designed for 50 Ω load) Output Noise ca. 20 mV peak-peak or 3 mV rms (@ 50 Ω load, no signal on detector)
Power Supply	Supply Voltage $\pm 15\text{ V}$ Supply Current $\pm 50\text{ mA typ.}$ (depends on operating conditions, recommended power supply capability minimum $\pm 150\text{ mA}$)
Case	Weight 210 g (0.5 lbs) Material AlMg4.5Mn, nickel-plated
Temperature Range	Storage Temperature - 40 ... + 100 °C Operating Temperature 0 ... + 60 °C

Absolute Maximum Ratings	Optical Input Power 20 mW Power Supply Voltage $\pm 22\text{ V}$
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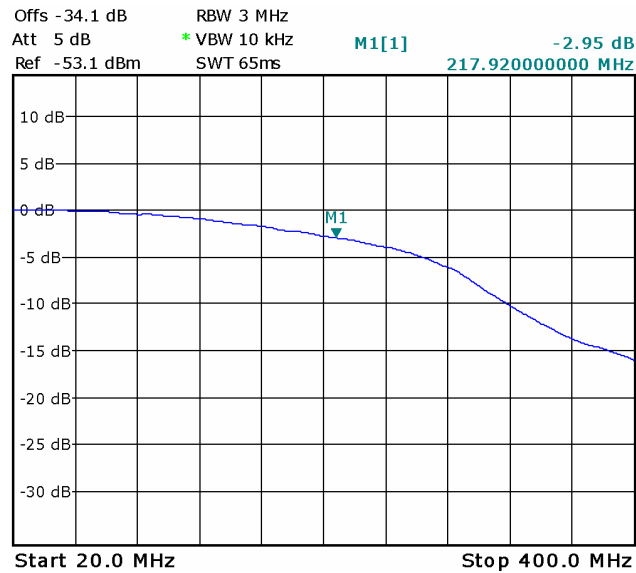
Connectors	Input HCA-S-200M-SI-FS 25 mm round flange for free space applications HCA-S-200M-SI-FC FC fiber optic receptacle HCA-S-200M-SI-SMA SMA fiber optic receptacle Output BNC Power Supply LEMO series 1S, 3-pin fixed socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND
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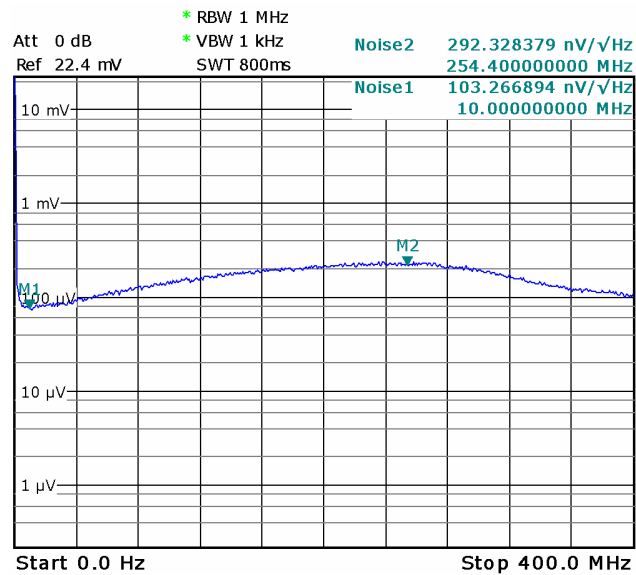
200 MHz Photoreceiver with Si PIN Photodiode

Typical Performance Characteristics

Frequency Response



Noise Spectrum



Note: Spectral noise data is measured at the amplifier output with no signal on the photodiode. To determine the spectral input noise divide the measured output noise by the amplifier conversion gain.

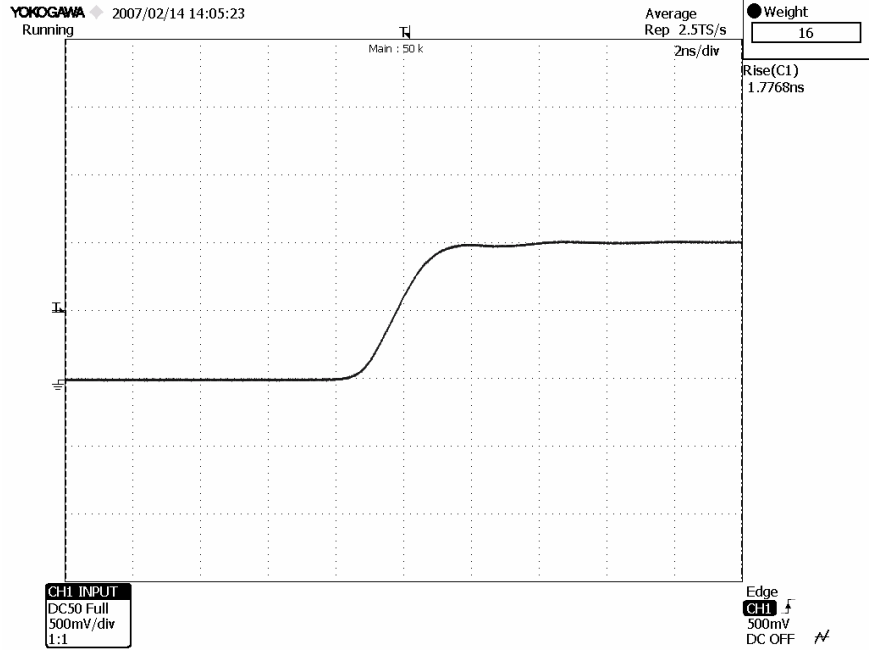
Conversion gain (V/W) = amplifier gain (20,000 V/A) x photo sensitivity (A/W).

Marker	Frequency	Output Noise	Resulting Input Noise (NEP)
1	10 MHz	103 nV/√Hz	9.4 pW/√Hz (@ 800 nm)
2	254 MHz	292 nV/√Hz	27 pW/√Hz (@ 800 nm)

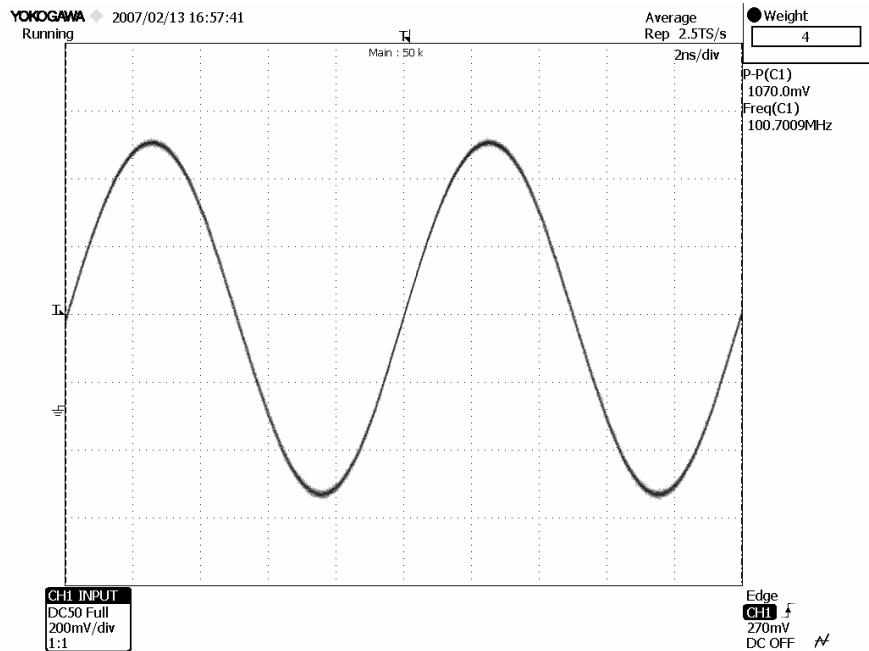
200 MHz Photoreceiver with Si PIN Photodiode

Typical Performance Characteristics
(continued)

Pulse Response to Square Wave Input Signal
(with 16 times averaging)



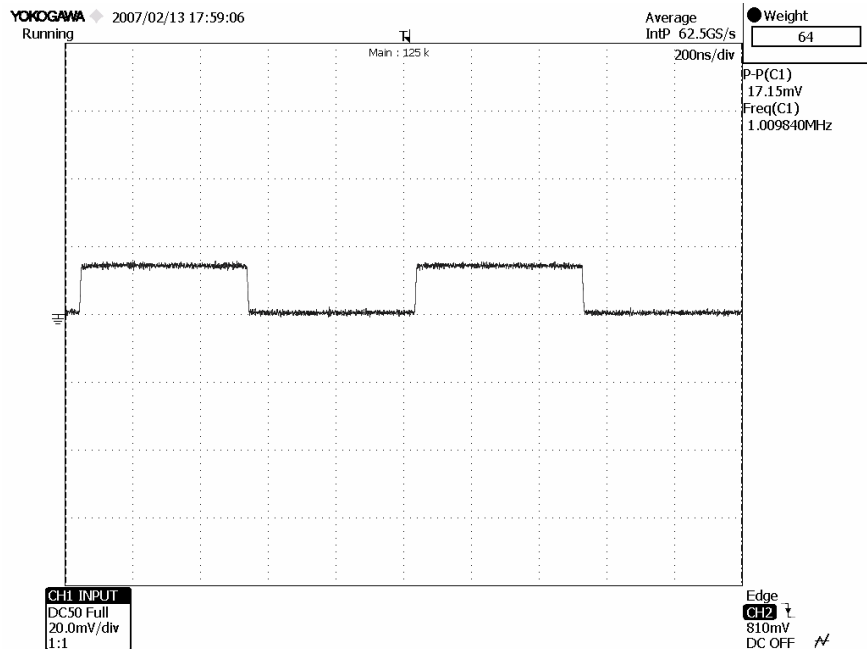
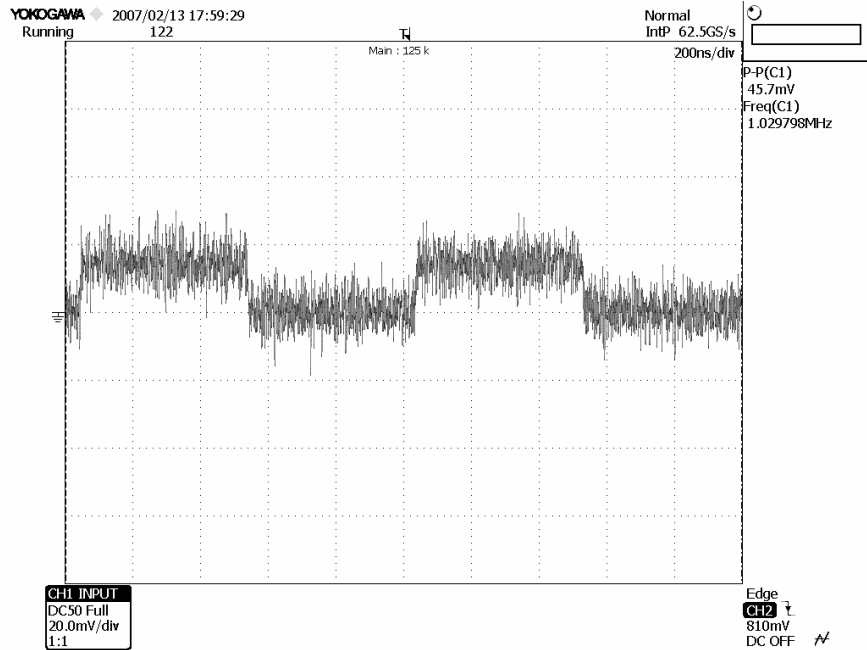
Large Signal Response
output signal for 100 MHz, 100 μ W modulated optical input signal
(with 4 times averaging)



200 MHz Photoreceiver with Si PIN Photodiode

Typical Performance Characteristics (continued)

Small Signal Response
output signal for 1.5 μ W modulated optical input signal, 1 MHz square wave (without (top) and with 64 times averaging (bottom))



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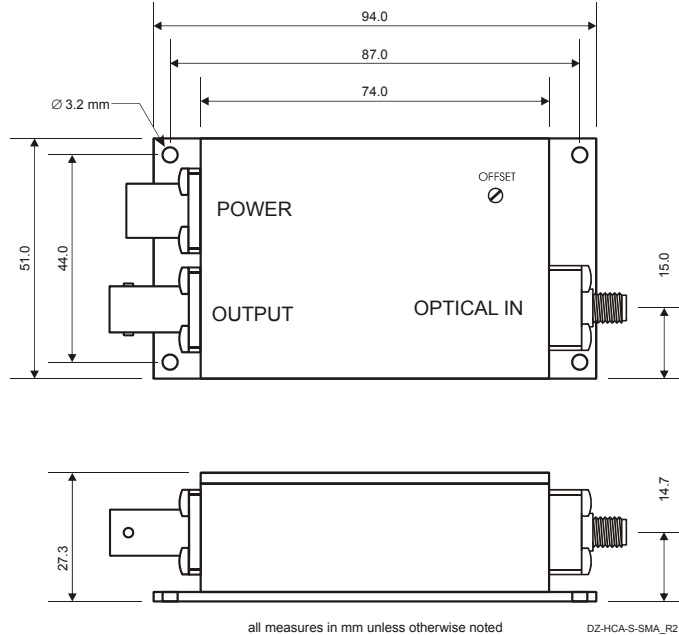
Available Models	HCA-S-200M-SI-FS HCA-S-200M-SI-FC HCA-S-200M-SI-SMA HCA-S	free space input FC fiber optic receptacle SMA fiber optic receptacle customized versions available on request
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Dimensions	<p>HCA-S-200M-SI-FS</p> <p>HCA-S-200M-SI-FC</p> <p>all measures in mm unless otherwise noted</p>	
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**200 MHz Photoreceiver with
Si PIN Photodiode**

Dimensions (continued)

HCA-S-200M-SI-SMA



FEMTO Messtechnik GmbH
Klosterstr. 64
D-10179 Berlin · Germany
Tel.: +49-(0)30-280 4711-0
Fax: +49-(0)30-280 4711-11
e-mail: info@femto.de
<http://www.femto.de>

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